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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details

| | |
|-------------------------|---|
| Product Status | Active |
| Architecture | MCU, FPGA |
| Core Processor | ARM® Cortex®-M3 |
| Flash Size | 256KB |
| RAM Size | 64KB |
| Peripherals | DDR, PCIe, SERDES |
| Connectivity | CANbus, Ethernet, I ² C, SPI, UART/USART, USB |
| Speed | 166MHz |
| Primary Attributes | FPGA - 50K Logic Modules |
| Operating Temperature | 0°C ~ 85°C (Tj) |
| Package / Case | 896-BGA |
| Supplier Device Package | 896-FBGA (31x31) |
| Purchase URL | https://www.e-xfl.com/product-detail/microchip-technology/m2s050ts-fgg896 |

1.9 Revision 3.0

In revision 3.0 of this document, the Theta B/C columns and FCS325 package was updated. For more information, see Table 9, page 10 (SAR 62002).

1.10 Revision 2.0

The following is a summary of the changes in revision 2.0 of this document.

- Table 1, page 4 was updated (SAR 59056).
- Table 7, page 8 temperature and data retention information was updated SAR (61363).
- Storage Operating Table was updated and split into three tables – Table 5, page 7, Table 7, page 8 (SAR 58725).
- Updated Theta B/C columns and FCS325 package in Table 9, page 10 (SAR 62002).
- Added 090-FCS325 thermal resistance to Table 9, page 10 (SAR 59384).
- TQ144 package was added to Table 9, page 10 (SAR 57708).
- Added PLL jitter data for the VF400 package (SAR 53162).
- Added Additional Worst Case IDD to Table 11, page 12 and Table 12, page 13 (SAR 59077).
- Table 13, page 13, Table 14, page 13, and Table 15, page 14 were added to verify Inrush currents (SAR 56348).
- Table 18, page 19 and Table 21, page 20 – I/O speeds were replaced.
- Max speed was changed in Table 41, page 26 (SAR 57221) and in Table 52, page 29 (SAR 57113).
- Minimum and Maximum DC/AC Input and Output Levels Specification, page 29 and Table 49, page 29–Table 57, page 31 were added.
- Added Cload to Table 89, page 39 (SAR 56238).
- Removed "Rs" information in DDR Timing Measurement Table 123, page 47, Table 133, page 49, and Table 144, page 52.
- Updated drive programming for M/B-LVDS outputs (SAR 58154).
- Added an inverter bubble to DDR_IN latch in Figure 10, page 70 (SAR 61418).
- QF waveform in Figure 11, page 71 was updated (SAR 59816).
- uSRAM Write Clock minimum values were updated in Table 237, page 86–Table 243, page 93 (SAR 55236).
- Fixed typo in the 32 kHz Crystal (XTAL) oscillator accuracy data section (SAR 59669).
- The "On-Chip Oscillator" section was split, and the Embedded NVM (eNVM) Characteristics, page 104 was added. Table 277, page 107–Table 281, page 109 were revised.(SARs 57898 and 59669).
- PLL VCP Frequency and conditions were added to Table 282, page 110 (SAR 57416).
- Fixed typo for PLL jitter data in the 100-400 MHz range (SAR 60727).
- Updated FCCC information in Table 282, page 110 and Table 283, page 111 (SAR 60799).
- Device 025 specifications were added to Table 283, page 111 (SAR 51625).
- JTAG Table 284, page 112 was replaced (SAR 51188).
- Flash*Freeze Table 293, page 119 was replaced (SAR 57828).
- Added support for HCSL I/O Standard for SERDES reference clocks in Table 300, page 123 and Table 301, page 123 (SAR 50748).
- Tir and Tif parameters were added to Table 303, page 124 (SAR 52203).
- Speed grade consistency was fixed in tables throughout the datasheet (SAR 50722).
- Added jitter attenuation information (SAR 59405).

1.11 Revision 1.0

The following is a summary of the changes in revision 1.0 of this document.

- The IGLOO2 v2 and the SmartFusion2 v5 datasheets are combined into this single product family datasheet.

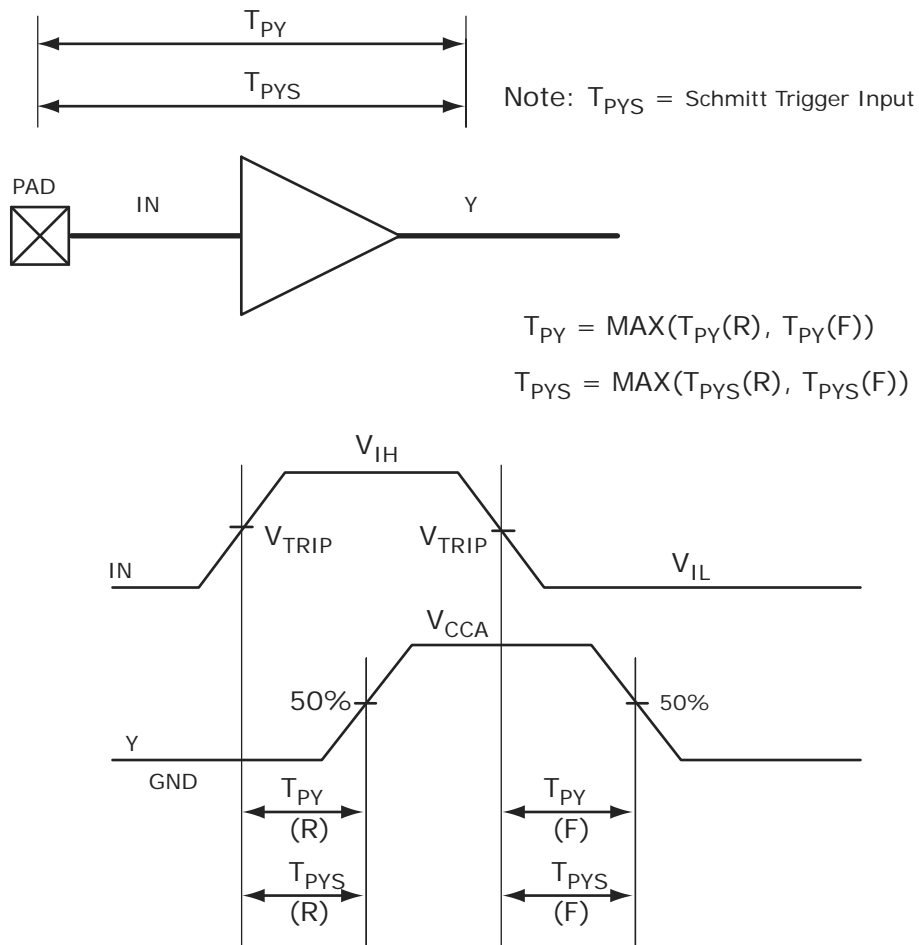
2.3.5 User I/O Characteristics

There are three types of I/Os supported in the IGLOO2 FPGA and SmartFusion2 SoC FPGA families: MSIO, MSIOD, and DDRIO I/O banks. The I/O standards supported by the different I/O banks is described in the I/Os section of the *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide*.

2.3.5.1 Input Buffer and AC Loading

The following figure shows the input buffer and AC loading.

Figure 3 • Input Buffer AC Loading



2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

Figure 4 • Output Buffer AC Loading

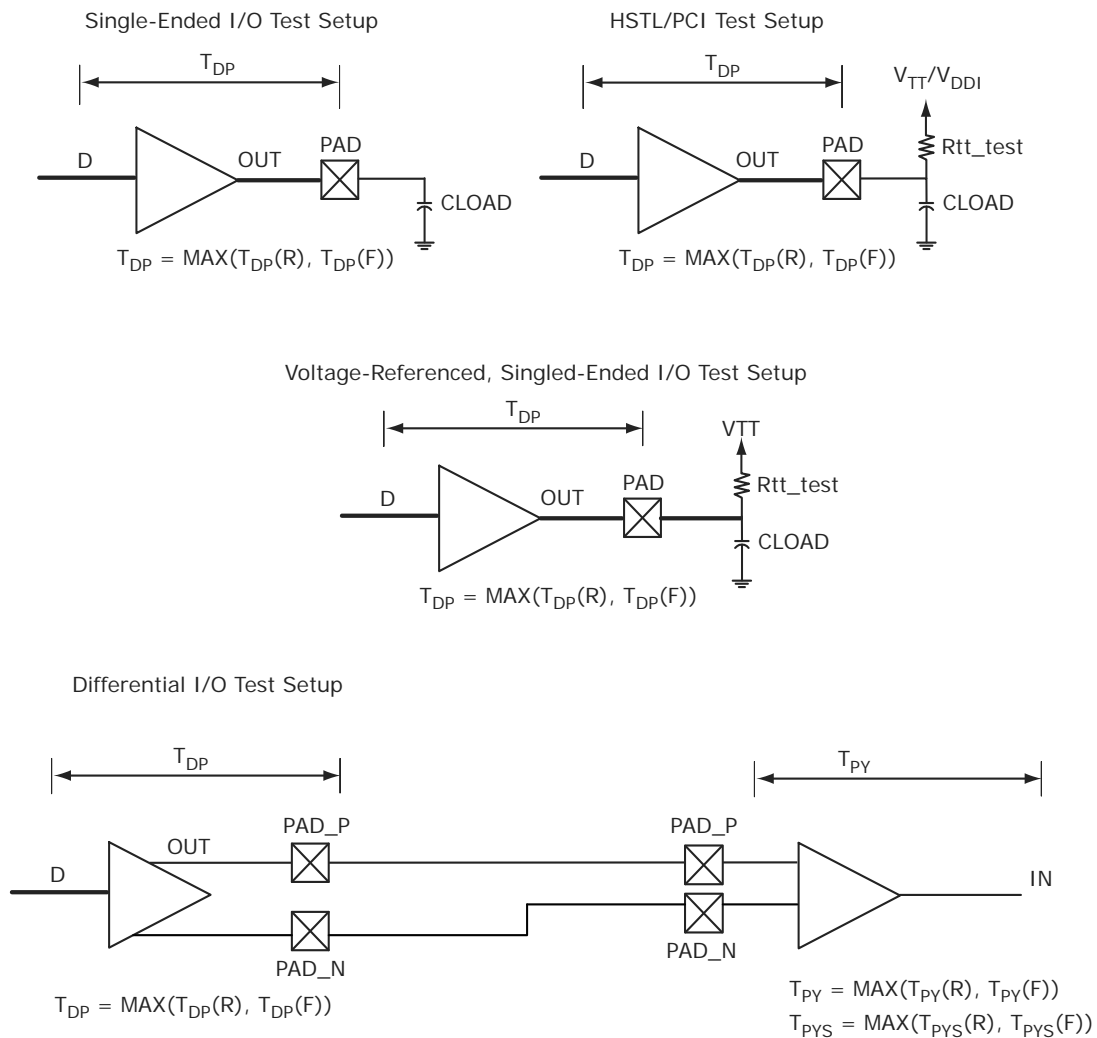


Table 19 • Maximum Data Rate Summary Table for Voltage-Referenced I/O in Worst-Case Industrial Conditions

| I/O | MSIO | MSIOD | DDRIO | Unit |
|------------|------|-------|-------|------|
| LPDDR | | | 400 | Mbps |
| HSTL1.5 V | | | 400 | Mbps |
| SSTL 2.5 V | 510 | 700 | 400 | Mbps |
| SSTL 1.8 V | | | 667 | Mbps |
| SSTL 1.5 V | | | 667 | Mbps |

Table 20 • Maximum Data Rate Summary Table for Differential I/O in Worst-Case Industrial Conditions

| I/O | MSIO | MSIOD | Unit |
|---------------------|------|-------|------|
| LVPECL (input only) | 900 | | Mbps |
| LVDS 3.3 V | 535 | | Mbps |
| LVDS 2.5 V | 535 | 700 | Mbps |
| RSDS | 520 | 700 | Mbps |
| BLVDS | 500 | | Mbps |
| MLVDS | 500 | | Mbps |
| Mini-LVDS | 520 | 700 | Mbps |

Table 21 • Maximum Frequency Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions

| I/O | MSIO | MSIOD | DDRIO | Unit |
|---------------------------|-------|-------|-------|------|
| PCI 3.3 V | 315 | | | MHz |
| LVTTTL 3.3 V | 300 | | | MHz |
| LVC MOS 3.3 V | 300 | | | MHz |
| LVC MOS 2.5 V | 205 | 210 | 200 | MHz |
| LVC MOS 1.8 V | 147.5 | 200 | 200 | MHz |
| LVC MOS 1.5 V | 80 | 110 | 118 | MHz |
| LVC MOS 1.2 V | 60 | 80 | 100 | MHz |
| LPDDR– LVC MOS 1.8 V mode | | | 200 | MHz |

Table 43 • LVCMOS 2.5 V AC Test Parameter Specifications

| Parameter | Symbol | Typ | Unit |
|--|------------|-----|----------------|
| Measuring/trip point for data path | V_{TRIP} | 1.2 | V |
| Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | R_{ENT} | 2K | $\Omega\sigma$ |
| Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | C_{ENT} | 5 | pF |
| Capacitive loading for data path (T_{DP}) | C_{LOAD} | 5 | pF |

Table 44 • LVCMOS 2.5 V Transmitter Drive Strength Specifications

| Output Drive Selection | | | VOH (V) | VOL (V) | IOH (at VOH) mA | IOL (at VOL) mA |
|------------------------|----------------|---|-----------------|---------|-----------------|-----------------|
| MSIO I/O Bank | MSIOD I/O Bank | DDRIO I/O Bank (With Software Default Fixed Code) | Min | Max | | |
| 2 mA | 2 mA | 2 mA | $V_{DDI} - 0.4$ | 0.4 | 2 | 2 |
| 4 mA | 4 mA | 4 mA | $V_{DDI} - 0.4$ | 0.4 | 4 | 4 |
| 6 mA | 6 mA | 6 mA | $V_{DDI} - 0.4$ | 0.4 | 6 | 6 |
| 8 mA | 8 mA | 8 mA | $V_{DDI} - 0.4$ | 0.4 | 8 | 8 |
| 12 mA | 12 mA | 12 mA | $V_{DDI} - 0.4$ | 0.4 | 12 | 12 |
| 16 mA | | 16 mA | $V_{DDI} - 0.4$ | 0.4 | 16 | 16 |

Note: For board design considerations, output slew rates extraction, detailed output buffer resistances, and I/V Curve, use the corresponding IBIS models located at:
www.microsemi.com/soc/download/ibis/default.aspx.

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 2.375\text{ V}$

Table 45 • LVCMOS 2.5 V Receiver Characteristics (Input Buffers)

| | On-Die Termination (ODT) | T_{PY} | | T_{PYS} | | Unit |
|-----------------------------------|-----------------------------|----------|-------|-----------|-------|------|
| | | -1 | -Std | -1 | -Std | |
| LVCMOS 2.5 V (for DDRIO I/O bank) | None | 1.823 | 2.145 | 1.932 | 2.274 | ns |
| LVCMOS 2.5 V (for MSIO I/O bank) | None | 2.486 | 2.925 | 2.495 | 2.935 | ns |
| LVCMOS 2.5 V (for MSIOD I/O bank) | None | 2.29 | 2.694 | 2.305 | 2.712 | ns |

Table 46 • LVCMOS 2.5 V Transmitter Characteristics for DDRIO Bank (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ}^1 | | T_{LZ}^1 | | Unit |
|------------------------|--------------|----------|-------|----------|-------|----------|-------|------------|-------|------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 3.657 | 4.302 | 3.393 | 3.991 | 3.675 | 4.323 | 3.894 | 4.582 | 3.552 | 4.18 | ns |
| | Medium | 3.374 | 3.97 | 3.139 | 3.693 | 3.396 | 3.995 | 3.635 | 4.277 | 3.253 | 3.828 | ns |
| | Medium fast | 3.239 | 3.811 | 3.036 | 3.572 | 3.261 | 3.836 | 3.519 | 4.141 | 3.128 | 3.681 | ns |
| | Fast | 3.224 | 3.793 | 3.029 | 3.563 | 3.246 | 3.818 | 3.512 | 4.132 | 3.119 | 3.67 | ns |

Table 53 • LVCMOS 1.8 V AC Calibrated Impedance Option

| Parameter | Symbol | Typ | Unit |
|---|----------|------------------------|----------|
| Supported output driver calibrated impedance (for DDRIO I/O bank) | Rodt_cal | 75, 60, 50, 33, 25, 20 | Ω |

Table 54 • LVCMOS 1.8 V AC Test Parameter Specifications

| Parameter | Symbol | Typ | Unit |
|---|-------------------|-----|----------|
| Measuring/trip point for data path | V _{TRIP} | 0.9 | V |
| Resistance for enable path (T _{ZH} , T _{ZL} , T _{HZ} , T _{LZ}) | R _{ENT} | 2k | Ω |
| Capacitive loading for enable path (T _{ZH} , T _{ZL} , T _{HZ} , T _{LZ}) | C _{ENT} | 5 | pF |
| Capacitive loading for data path (T _{DP}) | C _{LOAD} | 5 | pF |

Table 55 • LVCMOS 1.8 V Transmitter Drive Strength Specifications

| Output Drive Selection | | | V _{OH} (V) | V _{OL} (V) | IOH (at V _{OH}) | IOL (at V _{OL}) |
|------------------------|----------------|--------------------|-------------------------|---------------------|---------------------------|---------------------------|
| MSIO I/O Bank | MSIOD I/O Bank | DDRIO I/O Bank | Min | Max | mA | mA |
| 2 mA | 2 mA | 2 mA | V _{DDI} - 0.45 | 0.45 | 2 | 2 |
| 4 mA | 4 mA | 4 mA | V _{DDI} - 0.45 | 0.45 | 4 | 4 |
| 6 mA | 6 mA | 6 mA | V _{DDI} - 0.45 | 0.45 | 6 | 6 |
| 8 mA | 8 mA | 8 mA | V _{DDI} - 0.45 | 0.45 | 8 | 8 |
| 10 mA | 10 mA | 10 mA | V _{DDI} - 0.45 | 0.45 | 10 | 10 |
| 12 mA | | 12 mA | V _{DDI} - 0.45 | 0.45 | 12 | 12 |
| | | 16 mA ¹ | V _{DDI} - 0.45 | 0.45 | 16 | 16 |

1. 16 mA drive strengths, all slews, meets LPDDR JEDEC electrical compliance.

AC Switching Characteristics

Worst commercial-case conditions: T_J = 85 °C, V_{DD} = 1.14 V, V_{DDI} = 1.71 V

Table 56 • LVCMOS 1.8 V Receiver Characteristics (Input Buffers)

| | On-Die Termination (ODT) | T _{Py} | | T _{Pys} | | Unit |
|--|--------------------------|-----------------|-------|------------------|-------|------|
| | | -1 | -Std | -1 | -Std | |
| LVCMOS 1.8 V (for DDRIO I/O bank with Fixed Codes) | None | 1.968 | 2.315 | 2.099 | 2.47 | ns |
| | None | 2.898 | 3.411 | 2.883 | 3.393 | ns |
| | 50 | 3.05 | 3.59 | 3.044 | 3.583 | ns |
| LVCMOS 1.8 V (for MSIO I/O bank) | 75 | 2.999 | 3.53 | 2.987 | 3.516 | ns |
| | 150 | 2.947 | 3.469 | 2.933 | 3.452 | ns |
| | None | 2.611 | 3.071 | 2.598 | 3.057 | ns |
| LVCMOS 1.8 V (for MSIOD I/O bank) | 50 | 2.775 | 3.264 | 2.775 | 3.265 | ns |
| | 75 | 2.72 | 3.2 | 2.712 | 3.19 | ns |
| | 150 | 2.666 | 3.137 | 2.655 | 3.123 | ns |
| | None | 2.611 | 3.071 | 2.598 | 3.057 | ns |

Table 57 • LVCMOS 1.8 V Transmitter Characteristics for DDRIO I/O Bank with Fixed Code (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T _{DP} | | T _{ZL} | | T _{ZH} | | T _{HZ} ¹ | | T _{LZ} ¹ | | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 4.234 | 4.981 | 3.646 | 4.29 | 4.245 | 4.995 | 4.908 | 5.774 | 4.434 | 5.216 | ns |
| | Medium | 3.824 | 4.498 | 3.282 | 3.861 | 3.834 | 4.511 | 4.625 | 5.441 | 4.116 | 4.843 | ns |
| | Medium fast | 3.627 | 4.267 | 3.111 | 3.66 | 3.637 | 4.279 | 4.481 | 5.272 | 3.984 | 4.687 | ns |
| | Fast | 3.605 | 4.241 | 3.097 | 3.644 | 3.615 | 4.253 | 4.472 | 5.262 | 3.973 | 4.674 | ns |
| 4 mA | Slow | 3.923 | 4.615 | 3.314 | 3.9 | 3.918 | 4.61 | 5.403 | 6.356 | 4.894 | 5.757 | ns |
| | Medium | 3.518 | 4.138 | 2.961 | 3.484 | 3.515 | 4.135 | 5.121 | 6.025 | 4.561 | 5.366 | ns |
| | Medium fast | 3.321 | 3.907 | 2.783 | 3.275 | 3.317 | 3.903 | 4.966 | 5.843 | 4.426 | 5.206 | ns |
| | Fast | 3.301 | 3.883 | 2.77 | 3.259 | 3.296 | 3.878 | 4.957 | 5.831 | 4.417 | 5.196 | ns |
| 6 mA | Slow | 3.71 | 4.364 | 3.104 | 3.652 | 3.702 | 4.355 | 5.62 | 6.612 | 5.08 | 5.977 | ns |
| | Medium | 3.333 | 3.921 | 2.779 | 3.27 | 3.325 | 3.913 | 5.346 | 6.289 | 4.777 | 5.62 | ns |
| | Medium fast | 3.155 | 3.712 | 2.62 | 3.083 | 3.146 | 3.702 | 5.21 | 6.13 | 4.657 | 5.479 | ns |
| | Fast | 3.134 | 3.688 | 2.608 | 3.068 | 3.125 | 3.677 | 5.202 | 6.12 | 4.648 | 5.468 | ns |
| 8 mA | Slow | 3.619 | 4.258 | 3.007 | 3.538 | 3.607 | 4.244 | 5.815 | 6.841 | 5.249 | 6.175 | ns |
| | Medium | 3.246 | 3.819 | 2.686 | 3.16 | 3.236 | 3.807 | 5.542 | 6.52 | 4.936 | 5.807 | ns |
| | Medium fast | 3.066 | 3.607 | 2.525 | 2.971 | 3.054 | 3.593 | 5.405 | 6.359 | 4.811 | 5.66 | ns |
| | Fast | 3.046 | 3.584 | 2.513 | 2.957 | 3.034 | 3.57 | 5.401 | 6.353 | 4.803 | 5.651 | ns |
| 10 mA | Slow | 3.498 | 4.115 | 2.878 | 3.386 | 3.481 | 4.096 | 6.046 | 7.113 | 5.444 | 6.404 | ns |
| | Medium | 3.138 | 3.692 | 2.569 | 3.023 | 3.126 | 3.678 | 5.782 | 6.803 | 5.129 | 6.034 | ns |
| | Medium fast | 2.966 | 3.489 | 2.414 | 2.841 | 2.951 | 3.472 | 5.666 | 6.665 | 5.013 | 5.897 | ns |
| | Fast | 2.945 | 3.464 | 2.401 | 2.826 | 2.93 | 3.448 | 5.659 | 6.658 | 5.003 | 5.886 | ns |
| 12 mA | Slow | 3.417 | 4.02 | 2.807 | 3.303 | 3.401 | 4.002 | 6.083 | 7.156 | 5.464 | 6.428 | ns |
| | Medium | 3.076 | 3.618 | 2.519 | 2.964 | 3.063 | 3.604 | 5.828 | 6.856 | 5.176 | 6.089 | ns |
| | Medium fast | 2.913 | 3.427 | 2.376 | 2.795 | 2.898 | 3.41 | 5.725 | 6.736 | 5.072 | 5.966 | ns |
| | Fast | 2.894 | 3.405 | 2.362 | 2.78 | 2.879 | 3.388 | 5.715 | 6.724 | 5.064 | 5.957 | ns |
| 16 mA | Slow | 3.366 | 3.96 | 2.751 | 3.237 | 3.348 | 3.939 | 6.226 | 7.324 | 5.576 | 6.56 | ns |
| | Medium | 3.03 | 3.565 | 2.47 | 2.906 | 3.017 | 3.55 | 5.981 | 7.036 | 5.282 | 6.214 | ns |
| | Medium fast | 2.87 | 3.377 | 2.328 | 2.739 | 2.854 | 3.358 | 5.895 | 6.935 | 5.18 | 6.094 | ns |
| | Fast | 2.853 | 3.357 | 2.314 | 2.723 | 2.837 | 3.338 | 5.889 | 6.929 | 5.177 | 6.09 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

Table 58 • LVCMOS 1.8 V Transmitter Characteristics for MSIO I/O Bank

| Output Drive Selection | Slew Control | T _{DP} | | T _{ZL} | | T _{ZH} | | T _{HZ} ¹ | | T _{LZ} ¹ | | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 3.441 | 4.047 | 4.165 | 4.9 | 4.413 | 5.192 | 4.891 | 5.755 | 5.138 | 6.044 | ns |
| 4 mA | Slow | 3.218 | 3.786 | 3.642 | 4.284 | 3.941 | 4.636 | 5.665 | 6.665 | 5.568 | 6.551 | ns |
| 6 mA | Slow | 3.141 | 3.694 | 3.501 | 4.118 | 3.823 | 4.498 | 6.587 | 7.75 | 6.032 | 7.096 | ns |
| 8 mA | Slow | 3.165 | 3.723 | 3.319 | 3.904 | 3.654 | 4.298 | 6.898 | 8.115 | 6.216 | 7.313 | ns |
| 10 mA | Slow | 3.202 | 3.767 | 3.278 | 3.857 | 3.616 | 4.254 | 7.25 | 8.529 | 6.435 | 7.571 | ns |
| 12 mA | Slow | 3.277 | 3.855 | 3.175 | 3.736 | 3.519 | 4.139 | 7.392 | 8.697 | 6.538 | 7.692 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

Table 59 • LVCMOS 1.8 V Transmitter Characteristics for MSIOD I/O Bank

| Output Drive Selection | Slew Control | T _{DP} | | T _{ZL} | | T _{ZH} | | T _{HZ} ¹ | | T _{LZ} ¹ | | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 2.725 | 3.206 | 3.316 | 3.901 | 3.484 | 4.099 | 5.204 | 6.123 | 4.997 | 5.88 | ns |
| 4 mA | Slow | 2.242 | 2.638 | 2.777 | 3.267 | 2.947 | 3.466 | 5.729 | 6.74 | 5.448 | 6.41 | ns |
| 6 mA | Slow | 1.995 | 2.347 | 2.466 | 2.901 | 2.63 | 3.094 | 6.372 | 7.496 | 5.987 | 7.043 | ns |
| 8 mA | Slow | 2.001 | 2.354 | 2.44 | 2.87 | 2.6 | 3.058 | 6.633 | 7.804 | 6.193 | 7.286 | ns |
| 10 mA | Slow | 2.025 | 2.382 | 2.312 | 2.719 | 2.47 | 2.906 | 6.94 | 8.165 | 6.412 | 7.544 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

2.3.5.9 1.5 V LVCMOS

LVCMOS 1.5 is a general standard for 1.5 V applications and is supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs in compliance to the JEDEC specification JESD8-11A.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 60 • LVCMOS 1.5 V DC Recommended Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|------------------|-------|-----|-------|------|
| Supply voltage | V _{DDI} | 1.425 | 1.5 | 1.575 | V |

Table 61 • LVCMOS 1.5 V DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|---|----------------------|-------------------------|-------------------------|------|
| DC input logic high for (MSIOD and DDRIO I/O banks) | V _{IH} (DC) | 0.65 × V _{DDI} | 1.575 | V |
| DC input logic high (for MSIO I/O bank) | V _{IH} (DC) | 0.65 × V _{DDI} | 3.45 | V |
| DC input logic low | V _{IL} (DC) | -0.3 | 0.35 × V _{DDI} | V |
| Input current high ¹ | I _{IH} (DC) | | | - |
| Input current low ¹ | I _{IL} (DC) | | | - |

1. See Table 24, page 22.

Table 85 • LVCMOS 1.2 V Transmitter Characteristics for MSIOD I/O Bank (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T _{DP} | | T _{ZL} | | T _{ZH} | | T _{HZ} ¹ | | T _{LZ} ¹ | | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|--------|------------------------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 3.883 | 4.568 | 4.868 | 5.726 | 5.329 | 6.269 | 7.994 | 9.404 | 7.527 | 8.855 | ns |
| 4 mA | Slow | 3.774 | 4.44 | 4.188 | 4.926 | 4.613 | 5.426 | 8.972 | 10.555 | 8.315 | 9.782 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

2.3.5.11 3.3 V PCI/PCIX

Peripheral Component Interface (PCI) for 3.3 V standards specify support for 33 MHz and 66 MHz PCI bus applications.

Minimum and Maximum DC/AC Input and Output Levels Specification (Applicable to MSIO Bank Only)

Table 86 • PCI/PCI-X DC Recommended Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|------------------|------|-----|------|------|
| Supply voltage | V _{DDI} | 3.15 | 3.3 | 3.45 | V |

Table 87 • PCI/PCI-X DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|---------------------------------|----------------------|-----|------|------|
| DC input voltage | V _I | 0 | 3.45 | V |
| Input current high ¹ | I _{IH} (DC) | | | |
| Input current low ¹ | I _{IL} (DC) | | | |

1. See Table 24, page 22.

Table 88 • PCI/PCI-X DC Output Voltage Specification

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------------|-----------------|-----|-----------------------|-----|------|
| DC output logic high | V _{OH} | | Per PCI specification | | V |
| DC output logic low | V _{OL} | | Per PCI specification | | V |

Table 89 • PCI/PCI-X Minimum and Maximum AC Switching Speed

| Parameter | Symbol | Max | Unit | Conditions |
|-----------------------------------|------------------|-----|------|--------------------------------------|
| Maximum data rate (MSIO I/O bank) | D _{MAX} | 630 | Mbps | AC Loading: per JEDEC specifications |

Table 90 • PCI/PCI-X AC Test Parameter Specifications

| Parameter | Symbol | Typ | Unit |
|---|----------------------|--------------------------|------|
| Measuring/trip point for data path (falling edge) | V _{TRIP} | 0.615 × V _{DDI} | V |
| Measuring/trip point for data path (rising edge) | V _{TRIP} | 0.285 × V _{DDI} | V |
| Resistance for data test path | R _{TT_TEST} | 25 | Ω |
| Resistance for enable path (T _{ZH} , T _{ZL} , T _{HZ} , T _{LZ}) | R _{ENT} | 2K | Ω |
| Capacitive loading for enable path (T _{ZH} , T _{ZL} , T _{HZ} , T _{LZ}) | C _{ENT} | 5 | pF |
| Capacitive loading for data path (T _{DP}) | C _{LOAD} | 10 | pF |

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 3.0\text{ V}$

Table 91 • PCI/PCIX AC Switching Characteristics for Receiver for MSIO I/O Bank (Input Buffers)

| On-Die Termination (ODT) | T_{PY} | | T_{PYS} | | Unit |
|--------------------------|----------|-------|-----------|-------|------|
| | -1 | -Std | -1 | -Std | |
| None | 2.229 | 2.623 | 2.238 | 2.633 | ns |

Table 92 • PCI/PCIX AC switching Characteristics for Transmitter for MSIO I/O Bank (Output and Tristate Buffers)

| T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2.146 | 2.525 | 2.043 | 2.404 | 2.084 | 2.452 | 6.095 | 7.171 | 5.558 | 6.539 | ns |

2.3.6 Memory Interface and Voltage Referenced I/O Standards

This section describes High-Speed Transceiver Logic (HSTL) memory interface and voltage reference I/O standards.

2.3.6.1 High-Speed Transceiver Logic (HSTL)

The HSTL standard is a general purpose high-speed bus standard sponsored by IBM (EIA/JESD8-6). IGLOO2 FPGA and SmartFusion2 SoC FPGA devices support two classes of the 1.5 V HSTL. These differential versions of the standard require a differential amplifier input buffer and a push-pull output buffer.

Minimum and Maximum DC/AC Input and Output Levels Specification (Applicable to DDRIO Bank Only)

Table 93 • HSTL Recommended DC Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|-------------------------|-----------|-------|-------|-------|------|
| Supply voltage | V_{DDI} | 1.425 | 1.5 | 1.575 | V |
| Termination voltage | V_{TT} | 0.698 | 0.750 | 0.803 | V |
| Input reference voltage | V_{REF} | 0.698 | 0.750 | 0.803 | V |

Table 94 • HSTL DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|---------------------------------|---------------|-----------------|-----------------|------|
| DC input logic high | V_{IH} (DC) | $V_{REF} + 0.1$ | 1.575 | V |
| DC input logic low | V_{IL} (DC) | -0.3 | $V_{REF} - 0.1$ | V |
| Input current high ¹ | I_{IH} (DC) | | | |
| Input current low ¹ | I_{IL} (DC) | | | |

1. See Table 24, page 22.

2.3.6.6 Low Power Double Data Rate (LPDDR)

LPDDR reduced and full drive low power double data rate standards are supported in IGLOO2 FPGA and SmartFusion2 SoC FPGA I/Os. This standard requires a differential amplifier input buffer and a push-pull output buffer.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 139 • LPDDR DC Recommended DC Operating Conditions

| Parameter | Symbol | Min | Typ | Max |
|-------------------------|-----------|-------|-------|-------|
| Supply voltage | V_{DDI} | 1.71 | 1.8 | 1.89 |
| Termination voltage | V_{TT} | 0.838 | 0.900 | 0.964 |
| Input reference voltage | V_{REF} | 0.838 | 0.900 | 0.964 |

Table 140 • LPDDR DC Input Voltage Specification

| Parameter | Symbol | Min | Max |
|---------------------------------|---------------|----------------------|----------------------|
| DC input logic high | V_{IH} (DC) | $0.7 \times V_{DDI}$ | 1.89 |
| DC input logic low | V_{IL} (DC) | -0.3 | $0.3 \times V_{DDI}$ |
| Input current high ¹ | I_{IH} (DC) | | |
| Input current low ¹ | I_{IL} (DC) | | |

1. See Table 24, page 22.

Table 141 • LPDDR DC Output Voltage Specification Reduced Drive

| Parameter | Symbol | Min | Max |
|----------------------------------|----------------------|----------------------|----------------------|
| DC output logic high | V_{OH} | $0.9 \times V_{DDI}$ | |
| DC output logic low | V_{OL} | | $0.1 \times V_{DDI}$ |
| Output minimum source DC current | I_{OH} at V_{OH} | 0.1 | |
| Output minimum sink current | I_{OL} at V_{OL} | -0.1 | |

Table 142 • LPDDR DC Output Voltage Specification Full Drive¹

| Parameter | Symbol | Min | Max |
|----------------------------------|----------------------|----------------------|----------------------|
| DC output logic high | V_{OH} | $0.9 \times V_{DDI}$ | |
| DC output logic low | V_{OL} | | $0.1 \times V_{DDI}$ |
| Output minimum source DC current | I_{OH} at V_{OH} | 0.1 | |
| Output minimum sink current | I_{OL} at V_{OL} | -0.1 | |

1. To meet JEDEC Electrical Compliance, use LPDDR Full Drive Transmitter.

Table 143 • LPDDR DC Differential Voltage Specification

| Parameter | Symbol | Min |
|-------------------------------|---------------|----------------------|
| DC input differential voltage | V_{ID} (DC) | $0.4 \times V_{DDI}$ |

Table 168 • LVDS25 Receiver Characteristics for MSIOD I/O Bank (Input Buffers)

| On-Die Termination (ODT) | T_{PY} | | Unit |
|--------------------------|----------|-------|------|
| | -1 | -Std | |
| None | 2.554 | 3.004 | ns |
| 100 | 2.549 | 2.999 | ns |

Table 169 • LVDS25 Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)

| T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|----------|-------|----------|-------|----------|-------|----------|------|----------|-------|------|
| -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2.136 | 2.513 | 2.416 | 2.842 | 2.402 | 2.825 | 2.423 | 2.85 | 2.409 | 2.833 | ns |

Table 170 • LVDS25 Transmitter Characteristics for MSIOD I/O Bank (Output and Tristate Buffers)

| | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|------------------|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| No pre-emphasis | 1.61 | 1.893 | 1.749 | 2.058 | 1.735 | 2.041 | 1.897 | 2.231 | 1.866 | 2.195 | ns |
| Min pre-emphasis | 1.527 | 1.796 | 1.757 | 2.067 | 1.744 | 2.052 | 1.905 | 2.241 | 1.876 | 2.207 | ns |
| Med pre-emphasis | 1.496 | 1.76 | 1.765 | 2.077 | 1.751 | 2.06 | 1.914 | 2.252 | 1.884 | 2.216 | ns |

LVDS33 AC Switching Characteristics
Table 171 • LVDS33 Receiver Characteristics for MSIO I/O Bank (Input Buffers)

| On Die Termination (ODT) | T_{PY} | | Unit |
|--------------------------|----------|-------|------|
| | -1 | -Std | |
| None | 2.572 | 3.025 | ns |
| 100 | 2.569 | 3.023 | ns |

Table 172 • LVDS33 Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)

| T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|----------|-------|----------|------|----------|-------|----------|-------|----------|-------|------|
| -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 1.942 | 2.284 | 1.98 | 2.33 | 1.97 | 2.318 | 1.953 | 2.298 | 1.96 | 2.307 | ns |

2.3.7.5 RSDS

Reduced Swing Differential Signaling (RSDS) is similar to an LVDS high-speed interface using differential signaling. RSDS has a similar implementation to LVDS devices and is only intended for point-to-point applications.

Minimum and Maximum Input and Output Levels

Table 203 • RSDS Recommended DC Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|-----------|-------|-----|-------|------|
| Supply voltage | V_{DDI} | 2.375 | 2.5 | 2.625 | V |

Table 204 • RSDS DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|------------------|--------|-----|-------|------|
| DC input voltage | V_I | 0 | 2.925 | V |

Table 205 • RSDS DC Output Voltage Specification

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------------|----------|------|-------|------|------|
| DC output logic high | V_{OH} | 1.25 | 1.425 | 1.6 | V |
| DC output logic low | V_{OL} | 0.9 | 1.075 | 1.25 | V |

Table 206 • RSDS Differential Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|-----------------------------------|-----------|-----|-----|------|
| Differential output voltage swing | V_{OD} | 100 | 600 | mV |
| Output common mode voltage | V_{OCM} | 0.5 | 1.5 | V |
| Input common mode voltage | V_{ICM} | 0.3 | 1.5 | V |
| Input differential voltage | V_{ID} | 100 | 600 | mV |

Table 207 • RSDS Minimum and Maximum AC Switching Speed

| Parameter | Symbol | Max | Unit | Conditions |
|--|-----------|-----|------|---|
| Maximum data rate (for MSIO I/O bank) | D_{MAX} | 520 | Mbps | AC loading: 2 pF / 100 Ω differential load |
| Maximum data rate (for MSIOD I/O bank) | D_{MAX} | 700 | Mbps | AC loading: 2 pF / 100 Ω differential load |

Table 208 • RSDS AC Impedance Specifications

| Parameter | Symbol | Typ | Unit |
|------------------------|--------|-----|----------|
| Termination resistance | R_T | 100 | Ω |

Table 209 • RSDS AC Test Parameter Specifications

| Parameter | Symbol | Typ | Unit |
|--|------------|-------------|----------|
| Measuring/trip point for data path | V_{TRIP} | Cross point | V |
| Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | R_{ENT} | 2K | Ω |
| Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | C_{ENT} | 5 | pF |

2.3.9.4 Output DDR Module

Figure 12 • Output DDR Module

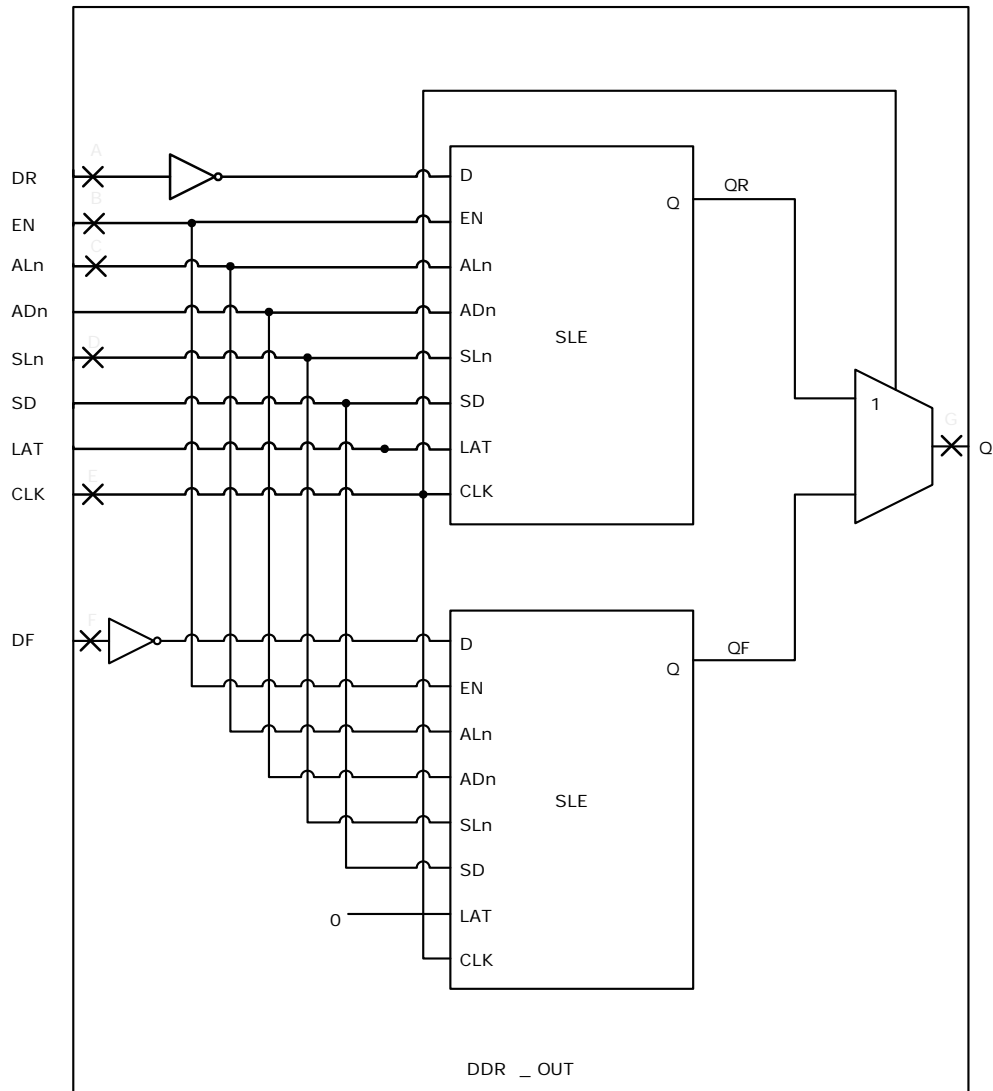


Table 222 • Output DDR Propagation Delays (continued)

| Symbol | Description | Measuring Nodes (from, to) | -1 | | Unit |
|------------------|--|-------------------------------|-------|-------|------|
| | | | -Std | | |
| $T_{DDROWAL}$ | Asynchronous load minimum pulse width for output DDR | C, C | 0.304 | 0.357 | ns |
| $T_{DDROCKMPWH}$ | Clock minimum pulse width high for the output DDR | E, E | 0.075 | 0.088 | ns |
| $T_{DDROCKMPWL}$ | Clock minimum pulse width low for the output DDR | E, E | 0.159 | 0.187 | ns |

2.3.10 Logic Element Specifications

2.3.10.1 4-input LUT (LUT-4)

The IGLOO2 and SmartFusion2 SoC FPGAs offer a fully permutable 4-input LUT. In this section, timing characteristics are presented for a sample of the library. For more details, see *SmartFusion2 and IGLOO2 Macro Library Guide*.

Figure 14 • LUT-4

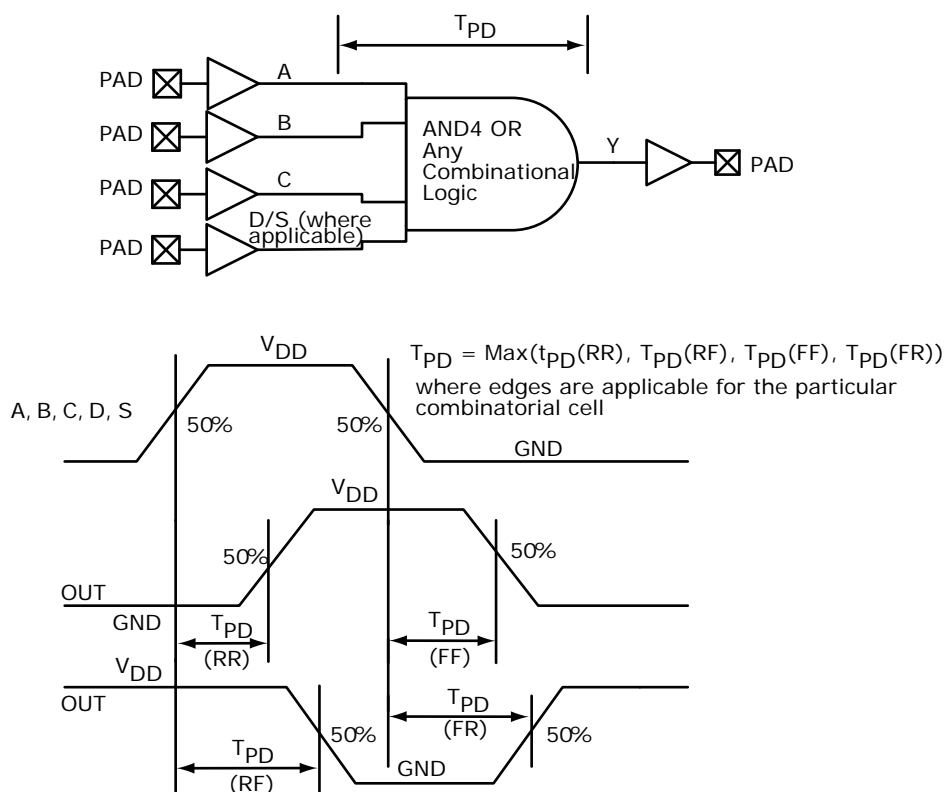


Table 248 • 2 Step IAP Programming (eNVM Only)

| M2S/M2GL | | | | | |
|-----------------|-------------------------|---------------------|----------------|---------------|-------------|
| Device | Image size Bytes | Authenticate | Program | Verify | Unit |
| 005 | 137536 | 2 | 37 | 5 | Sec |
| 010 | 274816 | 4 | 76 | 11 | Sec |
| 025 | 274816 | 4 | 78 | 10 | Sec |
| 050 | 278528 | 3 | 85 | 9 | Sec |
| 060 | 268480 | 5 | 76 | 22 | Sec |
| 090 | 544496 | 10 | 152 | 43 | Sec |
| 150 | 544496 | 10 | 153 | 44 | Sec |

Table 249 • 2 Step IAP Programming (Fabric and eNVM)

| M2S/M2GL | | | | | |
|-----------------|-------------------------|---------------------|----------------|---------------|-------------|
| Device | Image size Bytes | Authenticate | Program | Verify | Unit |
| 005 | 439296 | 6 | 56 | 11 | Sec |
| 010 | 842688 | 11 | 100 | 21 | Sec |
| 025 | 1497408 | 19 | 113 | 32 | Sec |
| 050 | 2695168 | 32 | 136 | 48 | Sec |
| 060 | 2686464 | 43 | 137 | 70 | Sec |
| 090 | 4190208 | 68 | 236 | 115 | Sec |
| 150 | 6682768 | 109 | 286 | 162 | Sec |

Table 250 • SmartFusion2 Cortex-M3 ISP Programming (Fabric Only)

| M2S/M2GL Device | Image size Bytes | Authenticate | Program | Verify | Unit |
|------------------------|-------------------------|---------------------|----------------|---------------|-------------|
| 005 | 302672 | 6 | 19 | 8 | Sec |
| 010 | 568784 | 10 | 26 | 14 | Sec |
| 025 | 1223504 | 21 | 39 | 29 | Sec |
| 050 | 2424832 | 39 | 60 | 50 | Sec |
| 060 | 2418896 | 44 | 65 | 54 | Sec |
| 090 | 3645968 | 66 | 90 | 79 | Sec |
| 150 | 6139184 | 108 | 140 | 128 | Sec |

Table 251 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only)

| M2S/M2GL Device | Image size Bytes | Authenticate | Program | Verify | Unit |
|------------------------|-------------------------|---------------------|----------------|---------------|-------------|
| 005 | 137536 | 3 | 42 | 4 | Sec |
| 010 | 274816 | 4 | 82 | 7 | Sec |
| 025 | 274816 | 4 | 82 | 8 | Sec |
| 050 | 278528 | 4 | 80 | 8 | Sec |
| 060 | 268480 | 6 | 80 | 8 | Sec |
| 090 | 544496 | 10 | 157 | 15 | Sec |

Table 251 • SmartFusion2 Cortex-M3 ISP Programming (eNVM Only) (continued)

| M2S/M2GL Device | Image size Bytes | Authenticate | Program | Verify | Unit |
|-----------------|------------------|--------------|---------|--------|------|
| 150 | 544496 | 10 | 158 | 15 | Sec |

Table 252 • SmartFusion2 Cortex-M3 ISP Programming (Fabric and eNVM)

| M2S/M2GL Device | Image size Bytes | Authenticate | Program | Verify | Unit |
|-----------------|------------------|--------------|---------|--------|------|
| 005 | 439296 | 9 | 61 | 11 | Sec |
| 010 | 842688 | 15 | 107 | 21 | Sec |
| 025 | 1497408 | 26 | 121 | 35 | Sec |
| 050 | 2695168 | 43 | 141 | 55 | Sec |
| 060 | 2686464 | 48 | 143 | 60 | Sec |
| 090 | 4190208 | 75 | 244 | 91 | Sec |
| 150 | 6682768 | 117 | 296 | 141 | Sec |

Table 253 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric Only)

| M2S/M2GL Device | Auto Programming | Auto Update | Programming Recovery | Unit |
|-----------------|------------------|---------------|----------------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 47 | 27 | 28 | Sec |
| 010 | 77 | 35 | 35 | Sec |
| 025 | 150 | 42 | 41 | Sec |
| 050 | 33 ¹ | Not Supported | Not Supported | Sec |
| 060 | 291 | 83 | 82 | Sec |
| 090 | 427 | 109 | 108 | Sec |
| 150 | 708 | 157 | 160 | Sec |

1. Auto Programming in 050 device is done through SC_SPI, and SPI CLK is set to 6.25 MHz.

Table 254 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (eNVM Only)

| M2S/M2GL Device | Auto Programming | Auto Update | Programming Recovery | Unit |
|-----------------|------------------|---------------|----------------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 41 | 48 | 49 | Sec |
| 010 | 86 | 87 | 87 | Sec |
| 025 | 87 | 85 | 86 | Sec |
| 050 | 85 | Not Supported | Not Supported | Sec |
| 060 | 78 | 86 | 86 | Sec |
| 090 | 154 | 162 | 162 | Sec |

Table 254 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (eNVM Only) (continued)

| M2S/M2GL Device | Auto Programming | Auto Update | Programming Recovery | Unit |
|--------------------|---------------------|-------------|-------------------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 150 | 161 | 161 | 161 | Sec |

Table 255 • Programming Times with 100 kHz, 25 MHz, and 12.5 MHz SPI Clock Rates (Fabric and eNVM)

| M2S/M2GL Device | Auto Programming | Auto Update | Programming Recovery | Unit |
|--------------------|---------------------|---------------|-------------------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 47 | 27 | 28 | Sec |
| 010 | 77 | 35 | 35 | Sec |
| 025 | 150 | 42 | 41 | Sec |
| 050 | 33 ¹ | Not Supported | Not Supported | Sec |
| 060 | 291 | 83 | 82 | Sec |
| 090 | 427 | 109 | 108 | Sec |
| 150 | 708 | 157 | 160 | Sec |
| 005 | 41 | 48 | 49 | Sec |
| 010 | 86 | 87 | 87 | Sec |
| 025 | 87 | 85 | 86 | Sec |
| 050 | 85 | Not Supported | Not Supported | Sec |
| 060 | 78 | 86 | 86 | Sec |
| 090 | 154 | 162 | 162 | Sec |
| 150 | 161 | 161 | 161 | Sec |
| 005 | 87 | 67 | 66 | Sec |
| 010 | 161 | 113 | 113 | Sec |
| 025 | 229 | 120 | 121 | Sec |
| 050 | 112 | Not Supported | Not Supported | Sec |
| 060 | 368 | 161 | 158 | Sec |
| 090 | 582 | 261 | 260 | Sec |
| 150 | 867 | 309 | 310 | Sec |

1. Auto Programming in 050 device is done through SC_SPI, and SPI CLK is set to 6.25 MHz.

Table 265 • Programming Times with 100 kHz, 25 MHz. and 12.5 MHz SPI Clock Rates (Fabric Only)

| M2S/M2GL Device | Auto Programming | | | Unit |
|-----------------|------------------|---------------|---------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 69 | 49 | 50 | Sec |
| 010 | 99 | 57 | 57 | Sec |
| 025 | 150 | 64 | 63 | Sec |
| 050 | 55 ¹ | Not Supported | Not Supported | Sec |
| 060 | 313 | 105 | 104 | Sec |
| 090 | 449 | 131 | 130 | Sec |
| 150 | 730 | 179 | 183 | Sec |

1. Auto programming in 050 device is done through SC_SPI, and SPI CLK is set to 6.25 MHz.

Table 266 • Programming Times with 100 kHz, 25 MHz. and 12.5 MHz SPI Clock Rates (eNVM Only)

| M2S/M2GL Device | Auto Programming | | | Unit |
|-----------------|------------------|---------------|---------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 63 | 70 | 71 | Sec |
| 010 | 108 | 109 | 109 | Sec |
| 025 | 109 | 107 | 108 | Sec |
| 050 | 107 | Not Supported | Not Supported | Sec |
| 060 | 100 | 108 | 108 | Sec |
| 090 | 176 | 184 | 184 | Sec |
| 150 | 183 | 183 | 183 | Sec |

Table 267 • Programming Times with 100 kHz, 25 MHz. and 12.5 MHz SPI Clock Rates (Fabric and eNVM)

| M2S/M2GL Device | Auto Programming | | | Unit |
|-----------------|------------------|---------------|---------------|------|
| | 100 kHz | 25 MHz | 12.5 MHz | |
| 005 | 109 | 89 | 88 | Sec |
| 010 | 183 | 135 | 135 | Sec |
| 025 | 251 | 142 | 143 | Sec |
| 050 | 134 | Not Supported | Not Supported | Sec |
| 060 | 390 | 183 | 180 | Sec |
| 090 | 604 | 283 | 282 | Sec |
| 150 | 889 | 331 | 332 | Sec |

The following table lists the SerDes reference clock AC specifications in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 299 • SerDes Reference Clock AC Specifications

| Parameter | Symbol | Min | Max | Unit |
|---------------------------------|---------------|------|------|------|
| Reference clock frequency | F_{REFCLK} | 100 | 160 | MHz |
| Reference clock rise time | T_{RISE} | 0.6 | 4 | V/ns |
| Reference clock fall time | T_{FALL} | 0.6 | 4 | V/ns |
| Reference clock duty cycle | T_{CYC} | 40 | 60 | % |
| Reference clock mismatch | $M_{MREFCLK}$ | -300 | 300 | ppm |
| Reference spread spectrum clock | SSC_{ref} | 0 | 5000 | ppm |

Table 300 • HCSL Minimum and Maximum DC Input Levels (Applicable to SerDes REFCLK Only)

| Parameter | Symbol | Min | Typ | Max | Unit |
|--|-------------|-------|-----|-------|------|
| Recommended DC Operating Conditions | | | | | |
| Supply voltage | V_{DDI} | 2.375 | 2.5 | 2.625 | V |
| HCSL DC Input Voltage Specification | | | | | |
| DC Input voltage | V_I | 0 | | 2.625 | V |
| HCSL Differential Voltage Specification | | | | | |
| Input common mode voltage | V_{ICM} | 0.05 | | 2.4 | V |
| Input differential voltage | V_{IDIFF} | 100 | | 1100 | mV |

Table 301 • HCSL Minimum and Maximum AC Switching Speeds (Applicable to SerDes REFCLK Only)

| Parameter | Symbol | Min | Typ | Max | Unit |
|---------------------------------------|-----------|-----|-----|-----|----------|
| HCSL AC Specifications | | | | | |
| Maximum data rate (for MSIO I/O bank) | F_{MAX} | | | 350 | Mbps |
| HCSL Impedance Specifications | | | | | |
| Termination resistance | R_t | | 100 | | Ω |

2.3.31 SmartFusion2 Specifications

2.3.31.1 MSS Clock Frequency

The following table lists the maximum frequency for MSS main clock in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 302 • Maximum Frequency for MSS Main Clock

| Symbol | Description | -1 | -Std | Unit |
|--------|--|-----|------|------|
| M3_CLK | Maximum frequency for the MSS main clock | 166 | 142 | MHz |